# 2SB1221

### Silicon PNP epitaxial planar type

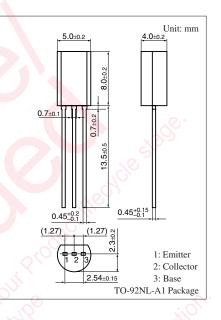
For general amplification

#### Features

- Low collector-emitter saturation voltage  $V_{CE(sat)}$
- Allowing supply with the radial taping

| Parameter                             | Symbol           | Rating      | Unit |  |  |  |  |
|---------------------------------------|------------------|-------------|------|--|--|--|--|
| Collector-base voltage (Emitter open) | V <sub>CBO</sub> | -250        | V    |  |  |  |  |
| Collector-emitter voltage (Base open) | V <sub>CEO</sub> | -200        | V    |  |  |  |  |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub> | -5          | V    |  |  |  |  |
| Collector current                     | I <sub>C</sub>   | -70         | mA   |  |  |  |  |
| Peak collector current                | I <sub>CP</sub>  | -100        | mA   |  |  |  |  |
| Collector power dissipation           | P <sub>C</sub>   | 1           | W    |  |  |  |  |
| Junction temperature                  | Tj               | 150         | °C   |  |  |  |  |
| Storage temperature                   | T <sub>stg</sub> | -55 to +150 | °C   |  |  |  |  |

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$



#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

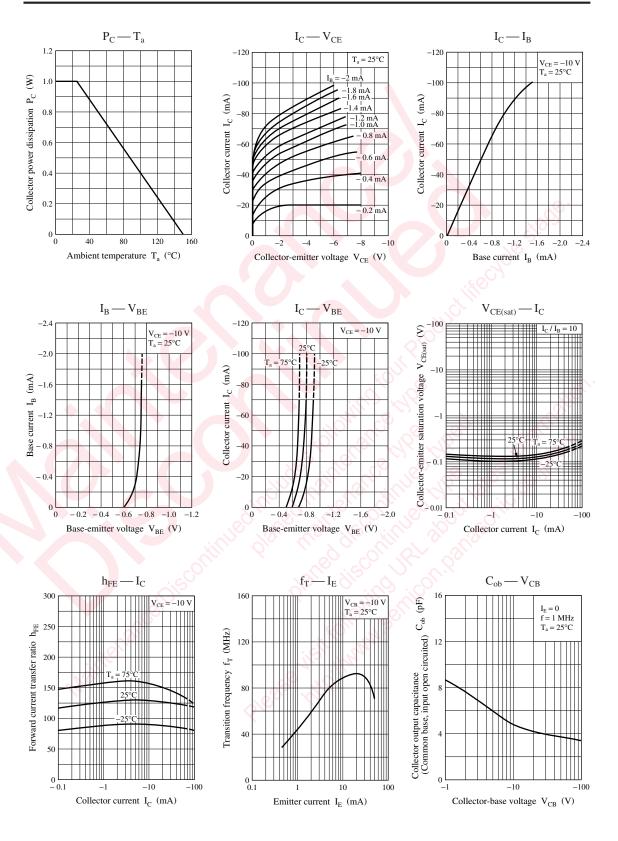
| Parameter                             | Symbol               | Conditions   | Min  | Тур | Max  | Unit |
|---------------------------------------|----------------------|--|------|-----|------|------|
| Collector-emitter voltage (Base open) | V <sub>CEO</sub>     | $I_{\rm C} = -100 \ \mu A, I_{\rm B} = 0$                          | -200 | ŝ   |      | V    |
| Emitter-base voltage (Collector open) | V <sub>EBO</sub>     | $I_{\rm E} = -1 \ \mu A, I_{\rm C} = 0$                            | -5   |     |      | V    |
| Forward current transfer ratio *      | h <sub>FE</sub>      | $V_{CE} = -10 \text{ V}, I_C = -5 \text{ mA}$                      | 30   |     | 220  |      |
| Collector-emitter saturation voltage  | V <sub>CE(sat)</sub> | $I_{\rm C} = -50$ mA, $I_{\rm B} = -5$ mA                          |      |     | -1.5 | V    |
| Transition frequency                  | f <sub>T</sub>       | $V_{CB} = -10 \text{ V}, I_E = 10 \text{ mA}, f = 200 \text{ MHz}$ | 50   | 80  |      | MHz  |
| Collector output capacitance          | C <sub>ob</sub>      | $V_{CB} = -10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$               |      | 5   | 10   | pF   |
| (Common base, input open circuited)   |                      | and the second second  |      |     |      |      |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

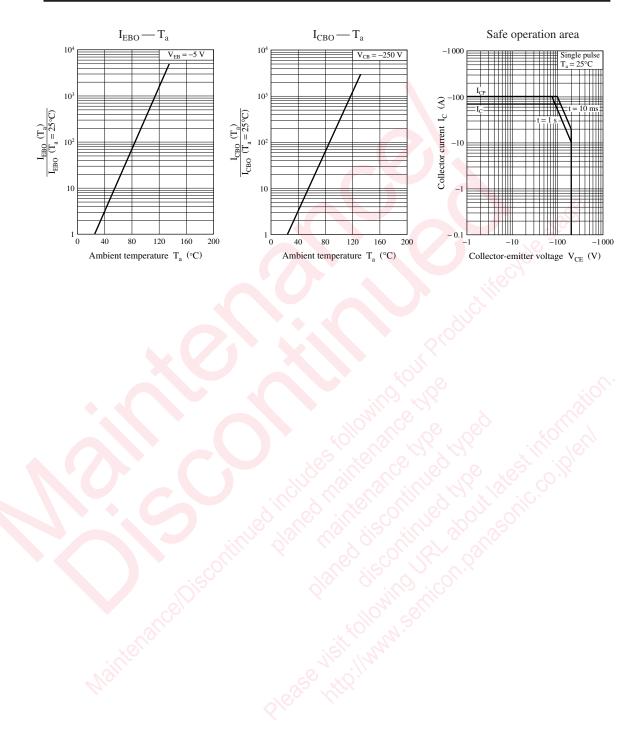
2. \*: Rank classification

| Rank            | Р         | Q O       | R          |
|-----------------|-----------|-----------|------------|
| h <sub>FE</sub> | 30 to 100 | 60 to 150 | 100 to 220 |

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